Unit in mm

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (PCT PROCESS)

# 2 S C 2 0 7 3 A

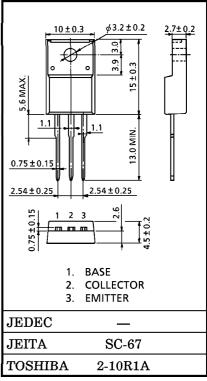
#### **POWER AMPLIFIER APPLICATIONS**

### **VERTICAL OUTPUT APPLICATIONS**

- Wide Safe Operating Area.
- Complementary to 2SA940A

## MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		$v_{CBO}$	150	V	
Collector-Emitter Voltage		$v_{CEO}$	150	V	
Emitter-Base Voltage		$v_{ m EBO}$	5	V	
Collector Current		$I_{\mathbf{C}}$	1.5	A	
Base Current		$I_{\mathbf{B}}$	0.5	A	
Collector Power	Ta = 25°C	Da	2.0	w	
Dissipation	$Tc = 25^{\circ}C$	$P_{\mathbf{C}}$	25	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Junction Temperature		$T_{j}$	150	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~150	$^{\circ}\mathrm{C}$	

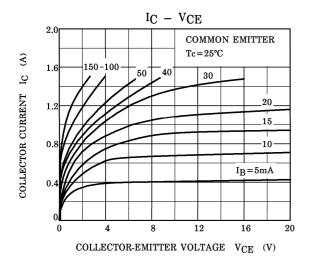


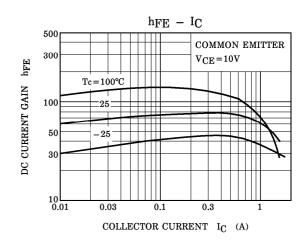
Weight: 1.7g (Typ.)

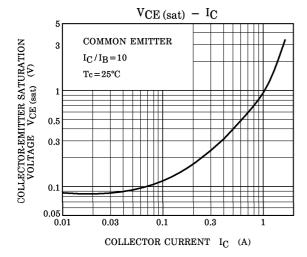
# ELECTRICAL CHARACTERISTICS (Tc = 25°C)

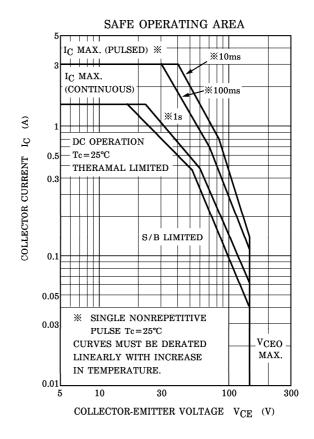
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 120V, I_{E} = 0$	_	_	10	$\mu$ <b>A</b>
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=5V, I_{C}=0$	_	_	10	$\mu$ <b>A</b>
DC Current Gain	${ m h_{FE}}$	$V_{CE} = 10V, I_{C} = 500 \text{mA}$	40	75	140	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	$I_{\rm C} = 500 {\rm mA}, \ I_{\rm B} = 50 {\rm mA}$	_	_	1.5	V
Base-Emitter Voltage	$V_{ m BE}$	$V_{CE} = 10V, I_{C} = 500 \text{mA}$	0.65	0.75	0.85	V
Transition Frequency	$ m f_{T}$	$V_{CE} = 10V, I_{C} = 500 \text{mA}$	_	4	_	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	35	_	рF

1 2001-11-05









2 2001-11-05

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